

FEATURES

- ✓ Protects 3.3, 5, 12, 15, 24 V Components
- ✓ Bidirectional
- ✓ Provides Electrically Isolated Protection
- ✓ 300 W @ 8/20 μ s
- ✓ Protects 4 Lines
- ✓ SO-8 Packaging
- ✓ This is a Pb - Free Device
- ✓ All SMC parts are traceable to the wafer lot
- ✓ Additional testing can be offered upon request

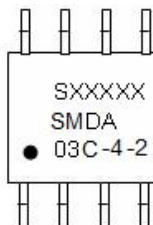
DESCRIPTION

The SMDAXXC-4-2 series of TVS array have been designed to provide bidirectional protection for sensitive electronics from damage due to voltage transients caused by electrostatic discharge (ESD), electrical fast transients (EFT), lightning and other voltage-induced transient events. The device can be used to protect combinations of four bidirectional lines.

APPLICATION

- ✓ Network Interfaces
- ✓ Portable Electronics
- ✓ Cellular Phone Terminals
- ✓ Audio/Video Inputs
- ✓ I/O Transceivers

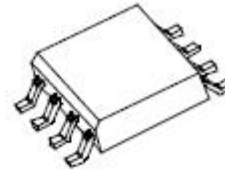
MARKING DIAGRAM



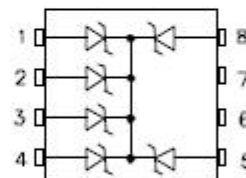
Cautions: Molding resin
Epoxy resin UL:94V-0

TVS ARRAY SERIES

SO-8



SCHEMATIC & PIN CONFIGURATION



MECHANICAL CHARACTERISTICS

- ✓ SO-8 Surface Mount Package
- ✓ Approximate Weight: 0.1 grams
- ✓ PIN #1 Indicator: DOT on top of package
- ✓ Packaging: Tubes or Tape & Reel per EIA Standard 481

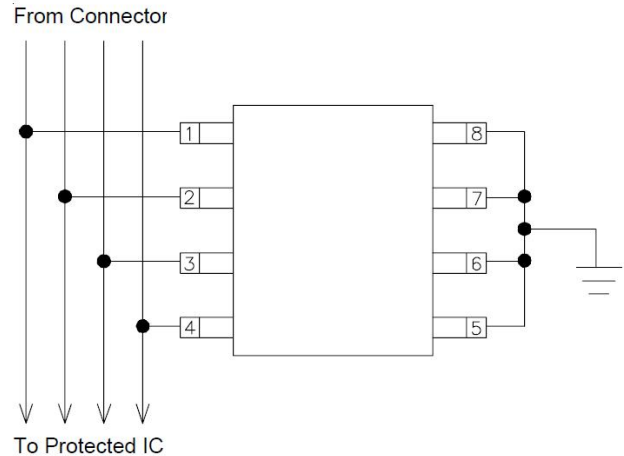
Where XXXXX is YYWWL

SMDA03C-4-2 = Part Name
S = S
YY = Year
WW = Week
L = Lot Number

Circuit Diagram

The SMDAxxC-4-2 can be configured to protect four data line. The options for connecting the devices is as follows:

- ✓ Bidirectional protection of four I/O line is achieved by connecting pins 1,2,3, and 4 to the data lines. Pins 5,6,7, and 8 are connected to ground. The ground connection should be made directly to the ground plane for best results. The path length is kept as short as possible to reduce the effects of parasitic inductance in the board trances. In this configuration, the device can withstand the maximum specified transient impulse on four lines simultaneously.



Ordering Information:

Device	Package	Shipping
SMDA03C-4-2 THRU SMDA24C-4-2	SO-8 (Pb-Free)	2500pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

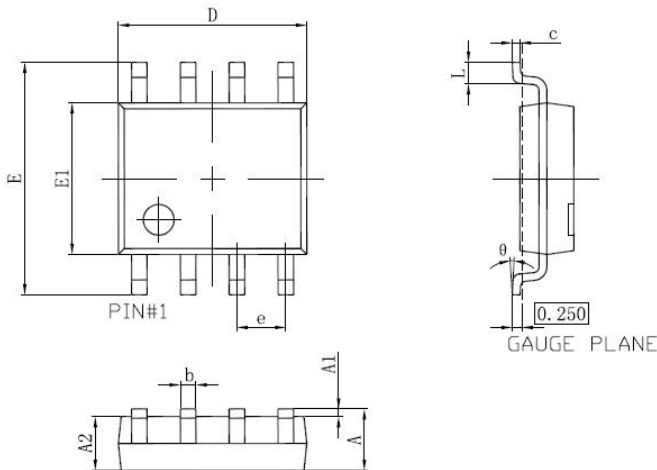
ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
P	Peak Pulse Power, 8/20 μ s Waveshape	300	W
T _J	Operating Temperature	-55 to +125	°C
T _{STG}	Storage Temperature	-55 to +150	°C
T _L	Lead Soldering Temperature	260 (10 Sec.)	°C

ELECTRICAL CHARACTERISTICS @ 25 °C

Part Number	Stand-off Voltage V_{wm} (V) Max	Breakdown Voltage V_{BR} @1mA (V) Min	Clamping Voltage V_c @ 1 A (V) Max	Leakage Current I_R @ V_{wm} (μ A) Max	Capacitance (f = 1MHz) C @ 0V (pF) Max	Temperature Coefficient of V_{BR} $a(V_{BR})$ mV/°C Max
SMDA03C-4-2	3.3	4	7	200	300	-5
SMDA05C-4-2	5.0	6	9.8	40	200	1
SMDA12C-4-2	12.0	13.3	19	1	75	8
SMDA15C-4-2	15.0	16.7	24	1	50	11
SMDA24C-4-2	24.0	26.7	43	1	35	28

PACKAGE OUTLINES & DEMENSIONS (SO-8)



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.007	0.010
D	4.800	5.000	0.189	0.197
e	1.270 (BSC)		0.050 (BSC)	
E	5.800	6.200	0.228	0.244
E1	3.800	4.000	0.150	0.157
L	0.400	1.270	0.016	0.031
θ	0°	8°	0°	8°

TYPICAL CHARACTERISTICS

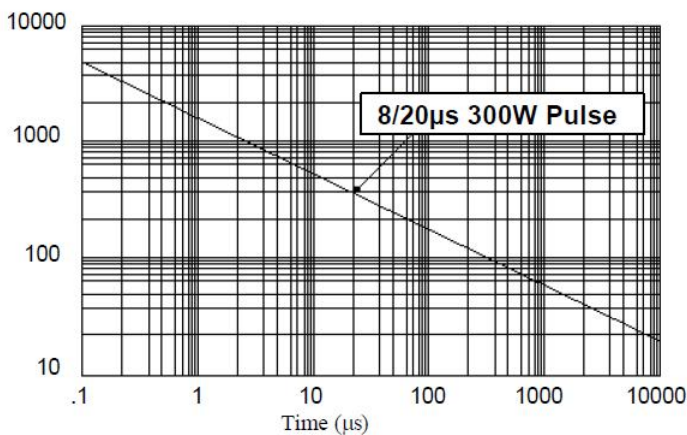


Figure 1. Peak Pulse Power Vs Pulse Time (μ s)

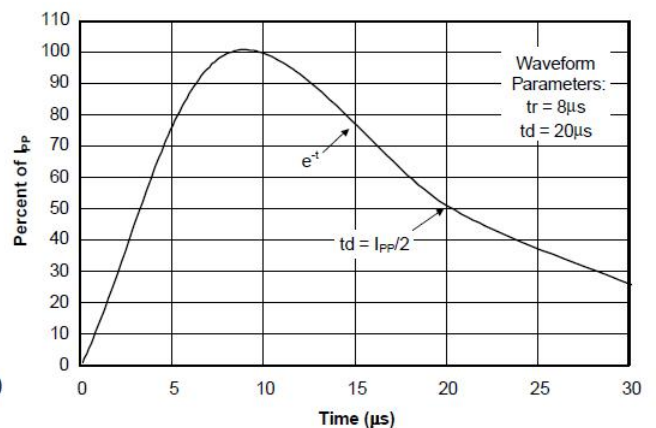


Figure 2. Pulse Wave Form



**Technical Data
Data Sheet N0299, Rev. -**

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